NSN 5962-01-341-7411

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View Online at https://aerobasegroup.com/nsn/5962-01-341-7411

Overall Height:

0.425 inches

Overall Width:

Between 0.590 inches and 0.630 inches

Body Length:

2.096 inches

Body Width:

Between 0.510 inches and 0.620 inches

Body Height:

0.210 inches

Maximum Power Dissipation Rating:

794.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Bipolar and burn in and programmed and monolithic and schottky and 3-state output

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

12 input

Case Outline Source And Designator:

D-6 mil-m-38510

Terminal Surface Treatment:

Solder

Product Name:

Microcircuit, digital, bipolar, programmable read only memory, 1k x 4

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Time Rating Per Chacteristic:

85.00 nanoseconds access

Memory Device Type:

Prom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

18 printed circuit

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Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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